NSN 5961-01-029-0989 Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
Between 0.240 inches and 0.260 inches
Terminal Length:
0.500 inches
Overall Diameter:
Between 0.335 inches and 0.370 inches
Component Name And Quantity:
2 transistor
Mounting Method:
Terminal
Terminal Circle Diameter:
0.200 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon all transistor
Voltage Rating In Volts Per Characteristic:
-35.0 drain to source voltage all transistor and -35.0 gate non-trigger voltage, dc all transistor and -40.0 gate to source voltage all
transistor
Current Rating Per Characteristic:
-50.00 milliamperes drain current all transistor
Power Rating Per Characteristic:
112.0 milliwatts total power dissipation all transistor
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius junction
Terminal Type And Quantity:
8 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0